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NSN 5961-00-851-5914 Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-851-5914
Inclosure Material:
Metal
Overall Length:
Between 1.281 inches and 1.405 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 1.240 inches and 1.250 inches
Thread Size:
0.750 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
10.0 gate voltage, dc
Current Rating Per Characteristic:
2.00 amperes source cutoff current minor and 235.00 amperes forward current, average of standard range and 3500.00 amperes forward
current, average preset
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 insulated wire lead w/terminal lug and 1 threaded stud and 2 uninsulated wire lead w/terminal lug
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig: